

# Power Matters<sup>™</sup>

117.00 W

Home ▶ 2N6127 (#23887)

## 2N6127 (#23887)

**Products** 

- ▶ Product Directory
- ▶ Parametric Search
- ► Applications Directory

Microsemi.

#### Overview

Power Dissipation, Total

Electrical Rating	Symbo	ol	Min		Тур	Max	Unit
Collector to Emitter Saturation Voltage	$V_{\text{CE(sat)}}$					0.90	V
DC Current Gain	HFE		30.00	)		120.00	
Maximum Electrical Rating		Sym		Min	Тур	Max	Unit
Maximum Electrical Rating Breakdown Voltage, Collector-Base (Emitter Open)		Ť	nbol (CBO)	Min	Тур	Max 100.00	Unit
<u> </u>		Ť		Min	Тур		
Breakdown Voltage, Collector-Base (Emitter Open)		V <sub>BR</sub>	(CBO)	Min	Тур	100.00	V

### This part can be found in the following product categories:

- → Discretes → Transistors → BJT( BiPolar Junction Transistor) → PNP Transistor
- $\bullet \ \ \, \text{Non-Radiation Hardened Devices} \ \bullet \ \, \text{Transistors} \ \bullet \ \, \text{BJT(BiPolar Junction Transistor)} \ \bullet \ \, \text{PNPTransistor}$

### **Related Links**

Technical support **Sales Contacts** Available Stock Sales Contacts RFQ/Samples

Products | Applications | Design Support | Company | Careers | Investors | Survey | Privacy Policy | Terms & Conditions | Product Disclaimer Copyright © 2015 Microsemi Corporation. All rights reserved. The Microsemi logo is a registered trademark of Microsemi Corporation.